



10-F012PNA015M7-P840C29

datasheet

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flowPIM 0		1200 V / 15 A
Features		
	<ul style="list-style-type: none">• IGBT M7 with low V_{CESat} and improved EMC behavior• Open emitter configuration• Compact and low inductive design• Built-in NTC	
Target applications		Schematic
	<ul style="list-style-type: none">• Industrial Drives	
Types		
	<ul style="list-style-type: none">• 10-F012PNA015M7-P840C29	

Maximum Ratings

 $T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
Inverter Switch				
Collector-emitter voltage	V_{CES}		1200	V
Collector current	I_C		15	A
Repetitive peak collector current	I_{CRM}	t_p limited by T_{jmax}	30	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	60	W
Gate-emitter voltage	V_{GES}		± 20	V
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$



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Maximum Ratings

$T_j = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Condition	Value	Unit
Inverter Diode				
Peak repetitive reverse voltage	V_{RRM}		1200	V
Continuous (direct) forward current	I_F		15	A
Repetitive peak forward current	I_{FRM}	T_j limited by T_{jmax}	30	A
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	45	W
Maximum junction temperature	T_{jmax}		175	$^\circ\text{C}$

Rectifier Diode

Peak repetitive reverse voltage	V_{RRM}		1600	V
Continuous (direct) forward current	I_F		25	A
Surge (non-repetitive) forward current	I_{FSM}	50 Hz Single Half Sine Wave $t_p = 10 \text{ ms}$	200	A
Surge current capability	I^2t		200	A^2s
Total power dissipation	P_{tot}	$T_j = T_{jmax}$ $T_s = 80^\circ\text{C}$	44	W
Maximum junction temperature	T_{jmax}		150	$^\circ\text{C}$

Module Properties

Thermal Properties

Storage temperature	T_{stg}		-40...+125	$^\circ\text{C}$
Operation temperature under switching condition	T_{jop}		-40...($T_{jmax} - 25$)	$^\circ\text{C}$

Isolation Properties

Isolation voltage	V_{isol}	DC Test Voltage* $t_p = 2 \text{ s}$	6000	V
		AC Voltage $t_p = 1 \text{ min}$	2500	V
Creepage distance			min. 12,7	mm
Clearance			min. 12,7	mm
Comparative Tracking Index	CTI		> 200	

*100 % tested in production



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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_c [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		

Inverter Switch

Static

Gate-emitter threshold voltage	$V_{GE(th)}$			10	0,0015	25	5,4	6,0	6,6	V
Collector-emitter saturation voltage	V_{CESat}		15		15	25 125 150		1,70 1,95 2,01	2,15	V
Collector-emitter cut-off current	I_{CES}		0	1200		25			60	µA
Gate-emitter leakage current	I_{GES}		20	0		25			500	nA
Internal gate resistance	r_g							none		Ω
Input capacitance	C_{ies}							2900		pF
Output capacitance	C_{oes}		0	10		25		120		
Reverse transfer capacitance	C_{res}							34		
Gate charge	Q_g		15	600	15	25		110		nC

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						1,60		K/W
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Dynamic

Turn-on delay time	$t_{d(on)}$	$R_{gon} = 32 \Omega$ $R_{goff} = 32 \Omega$	± 15	600	15	25 150		176 174		ns
Rise time	t_r					25 150		43 48		
Turn-off delay time	$t_{d(off)}$					25 150		191 218		
Fall time	t_f					25 150		119 127		
Turn-on energy (per pulse)	E_{on}					25 150		1,548 2,008		
Turn-off energy (per pulse)	E_{off}					25 150		0,925 1,322		



10-F012PNA015M7-P840C29

datasheet

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Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
			V_{GE} [V] V_{GS} [V]	V_{CE} [V] V_{DS} [V] V_F [V]	I_c [A] I_D [A] I_F [A]	T_j [°C]	Min	Typ	Max		

Inverter Diode

Static

Forward voltage	V_F				15	25 125 150		1,63 1,74 1,73	2,1	V
Reverse leakage current	I_R			1200		25			30	μA

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						2,11		K/W
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Dynamic

Peak recovery current	I_{RRM}	$di/dt = 293 \text{ A}/\mu\text{s}$ $di/dt = 244 \text{ A}/\mu\text{s}$	± 15	600	15	25 150		11 12		A
Reverse recovery time	t_{rr}					25 150		265 423		ns
Recovered charge	Q_r					25 150		1,549 2,592		μC
Reverse recovered energy	E_{rec}					25 150		0,488 0,938		mWs
Peak rate of fall of recovery current	$(di_{rf}/dt)_{max}$					25 150		92 52		$A/\mu\text{s}$

Rectifier Diode

Static

Forward voltage	V_F				25	25 125		1,22 1,21		V
Reverse leakage current	I_R			1600		25			50	μA

Thermal

Thermal resistance junction to sink	$R_{th(j-s)}$	$\lambda_{paste} = 3,4 \text{ W/mK}$ (PSX)						1,59		K/W
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10-F012PNA015M7-P840C29
datasheet

Characteristic Values

Parameter	Symbol	Conditions						Value			Unit
		V_{GE} [V]	V_{GS} [V]	V_{CE} [V]	V_{DS} [V]	I_c [A]	I_D [A]	T_j [°C]	Min	Typ	Max

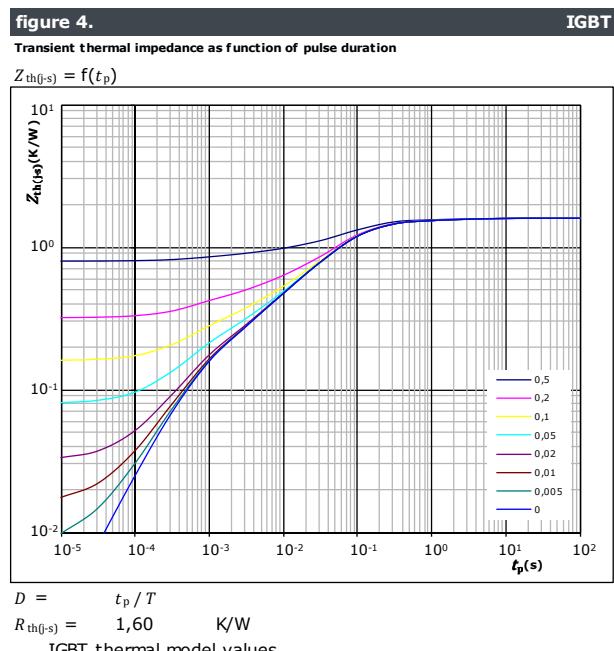
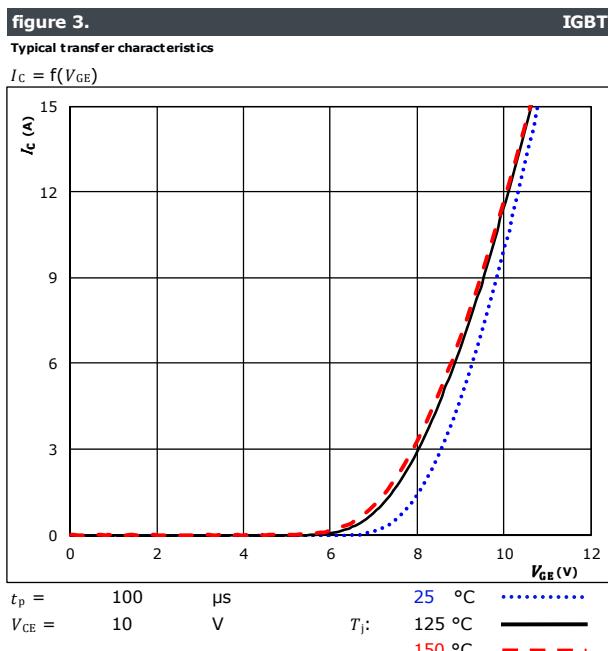
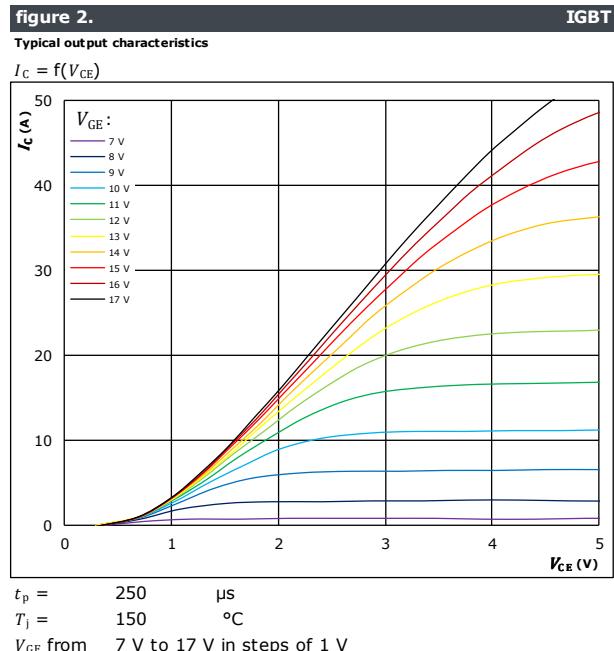
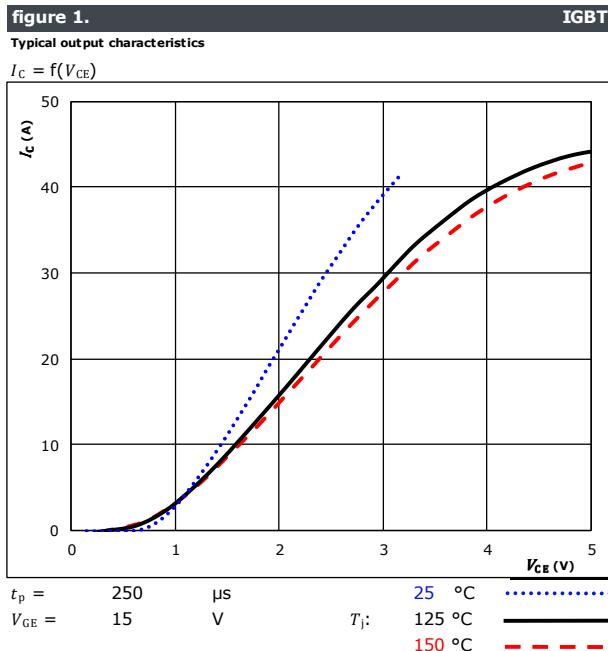
Thermistor

Rated resistance	R					25		22			kΩ
Deviation of R_{100}	$\Delta R/R$	$R_{100} = 1484 \Omega$				100	-5		5		%
Power dissipation	P					25		5			mW
Power dissipation constant						25		1,5			mW/K
B-value	$B_{(25/50)}$	Tol. ±1 %				25		3962			K
B-value	$B_{(25/100)}$	Tol. ±1 %				25		4000			K
Vincotech NTC Reference									I		



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Inverter Switch Characteristics

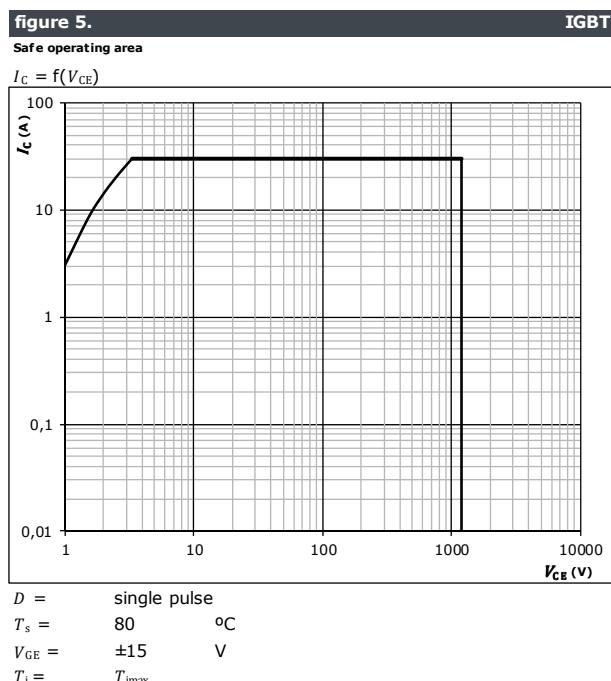




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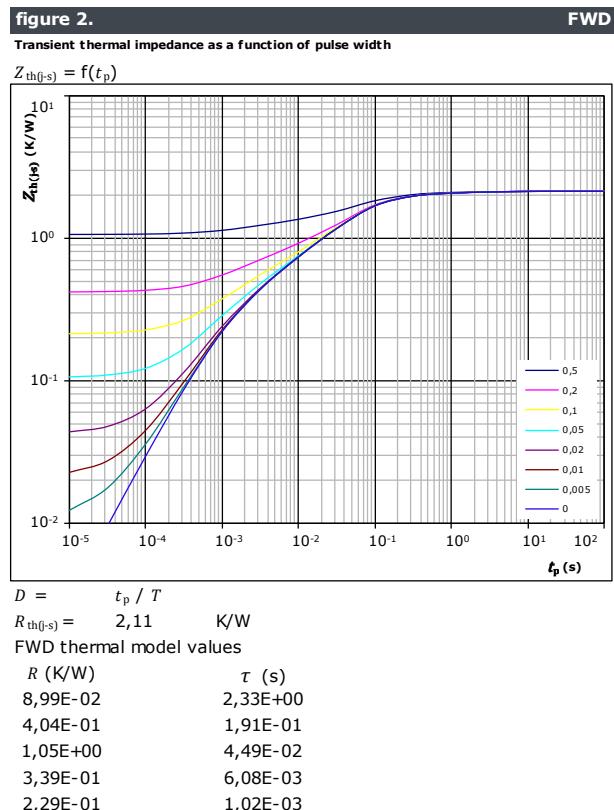
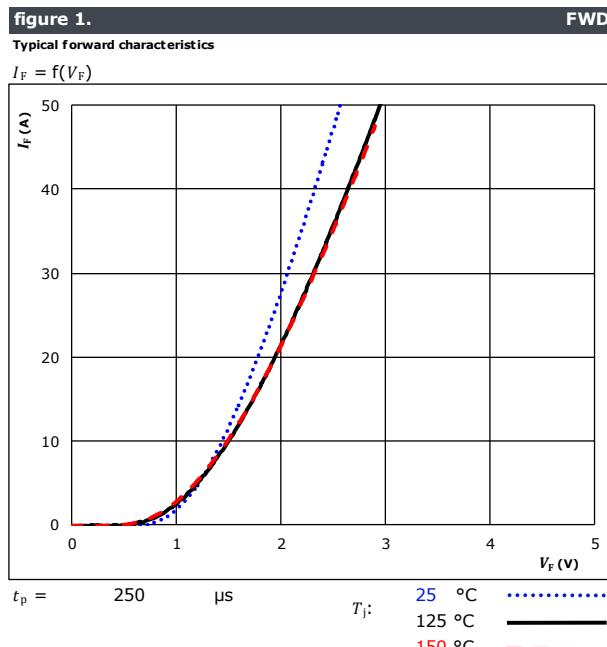
Inverter Switch Characteristics





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Inverter Diode Characteristics

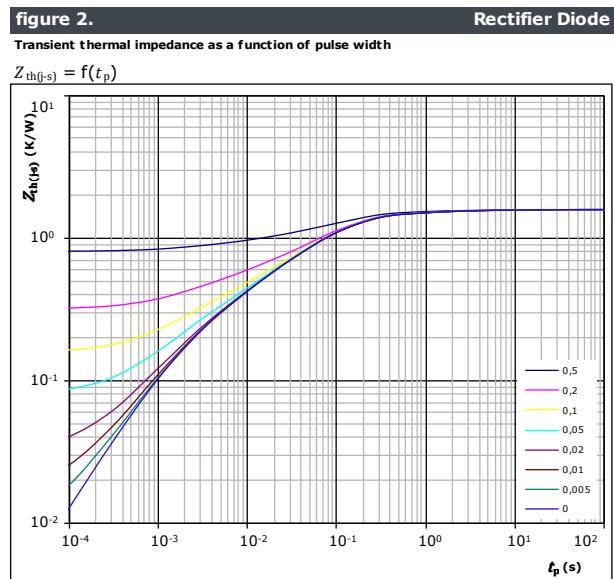
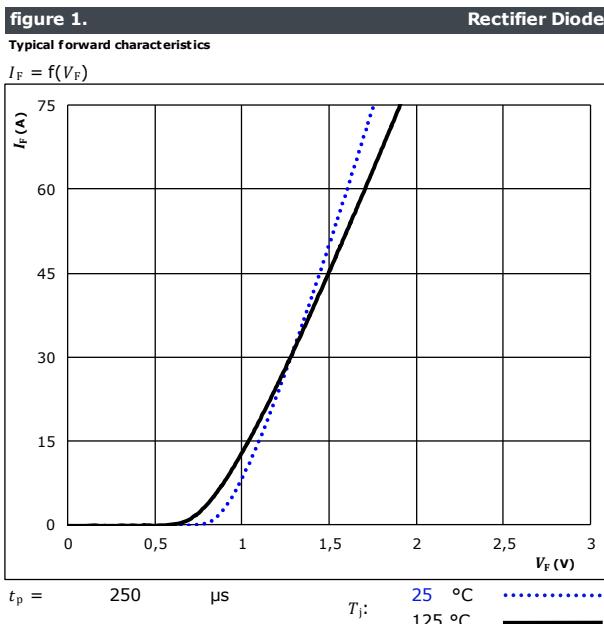




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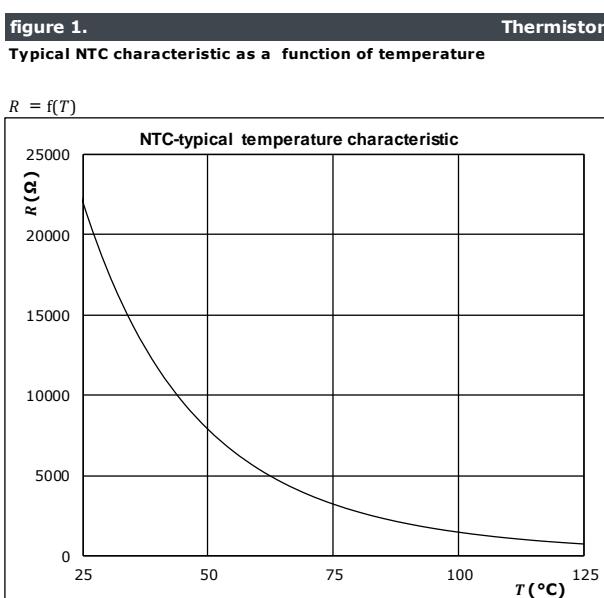
Rectifier Diode Characteristics



Diode thermal model values

R (K/W)	τ (s)
3,44E-02	9,66E+00
1,12E-01	1,22E+00
5,81E-01	1,45E-01
4,89E-01	5,05E-02
2,38E-01	9,26E-03
1,22E-01	1,79E-03
1,81E-02	7,88E-04

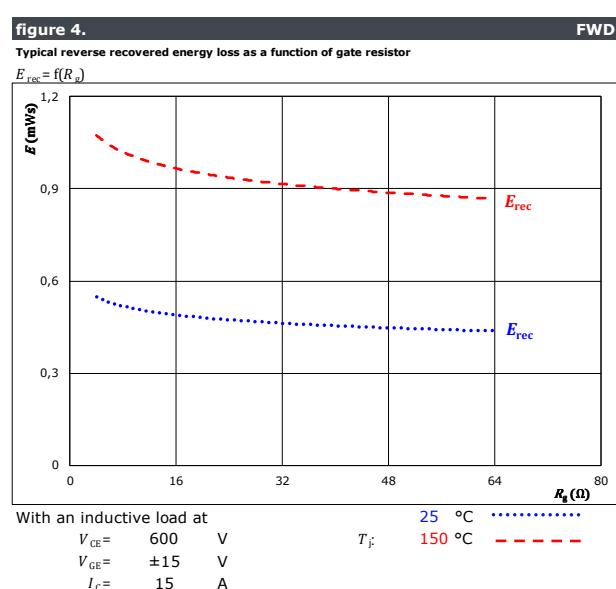
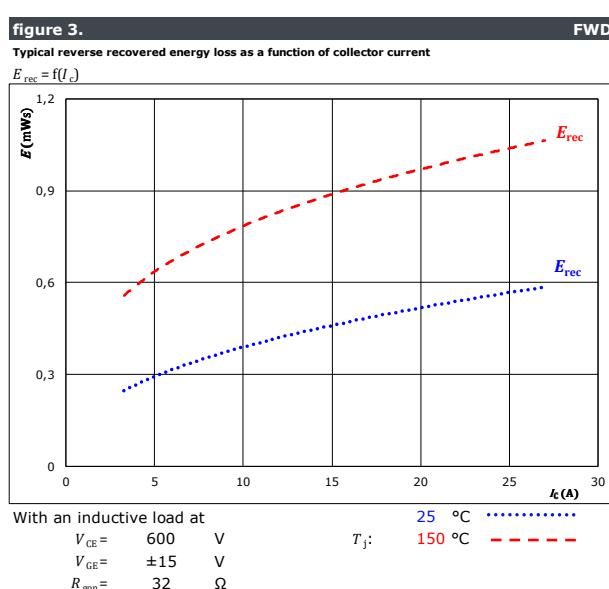
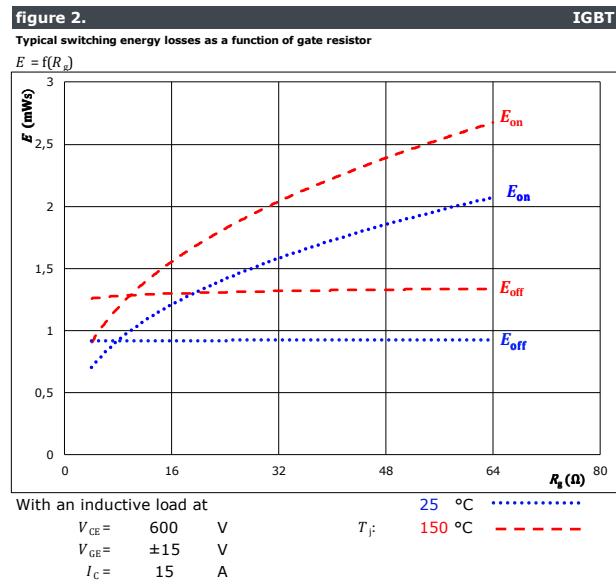
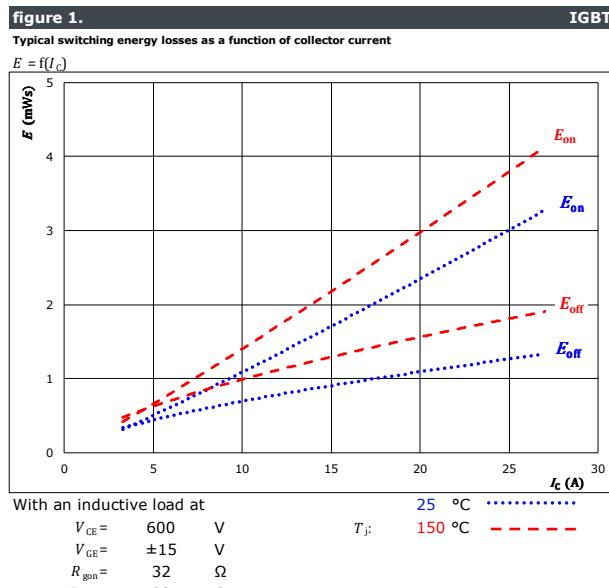
Thermistor Characteristics





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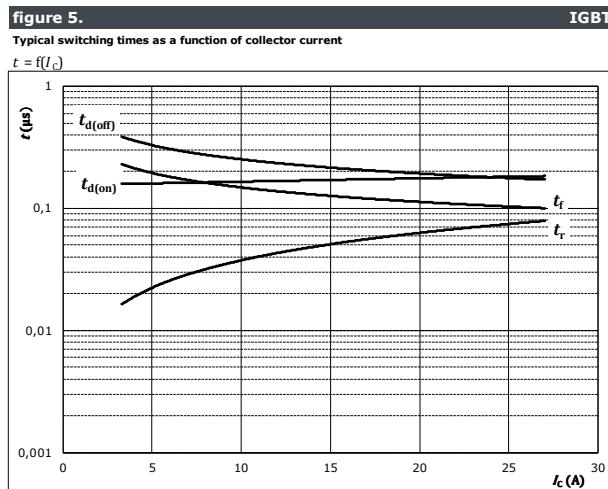
Inverter Switching Characteristics





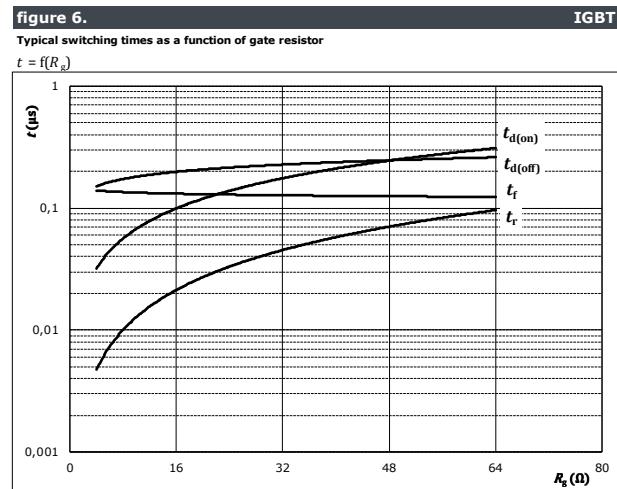
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Inverter Switching Characteristics



With an inductive load at

$T_j =$	150	°C
$V_{CE} =$	600	V
$V_{GE} =$	±15	V
$R_{gon} =$	32	Ω
$R_{goff} =$	32	Ω



With an inductive load at

$T_j =$	150	°C
$V_{CE} =$	600	V
$V_{GE} =$	±15	V
$I_c =$	15	A



At

$V_{CE} =$	600	V
$V_{GE} =$	±15	V
$R_{gon} =$	32	Ω
$T_j:$	25 °C
	150 °C	-----



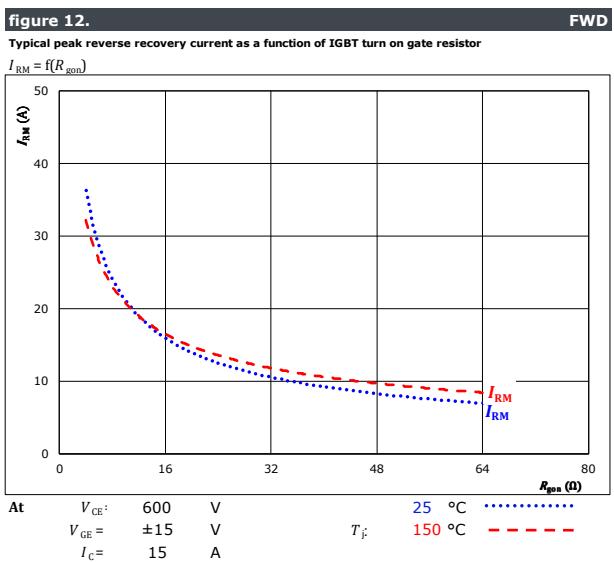
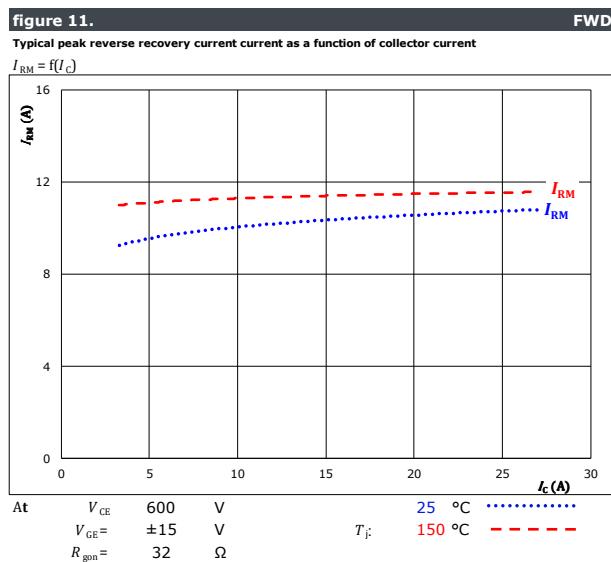
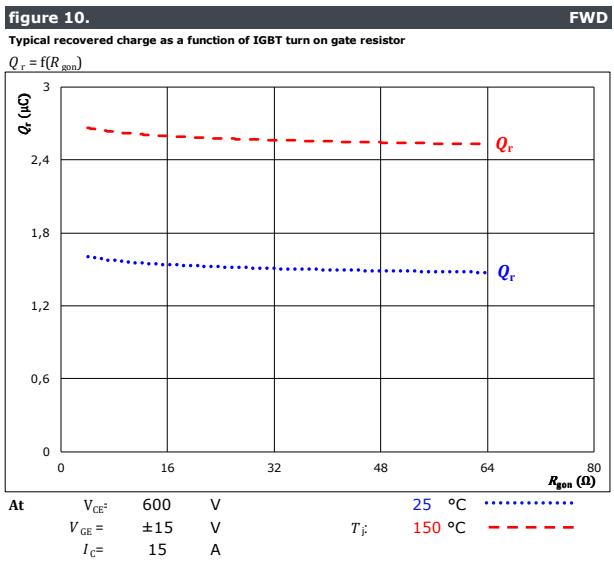
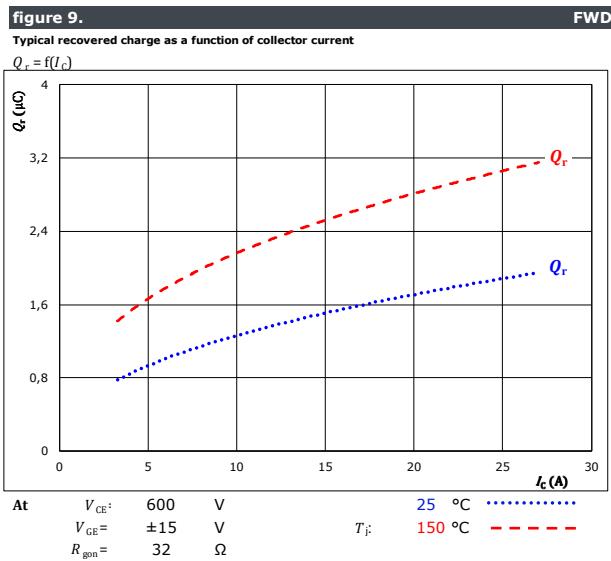
At	$V_{CE} =$	600	V
	$V_{GE} =$	±15	V
	$I_c =$	15	A



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10-F012PNA015M7-P840C29
datasheet

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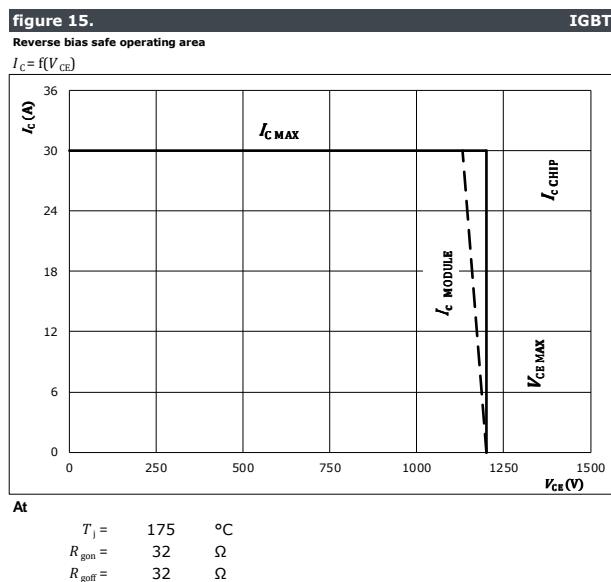
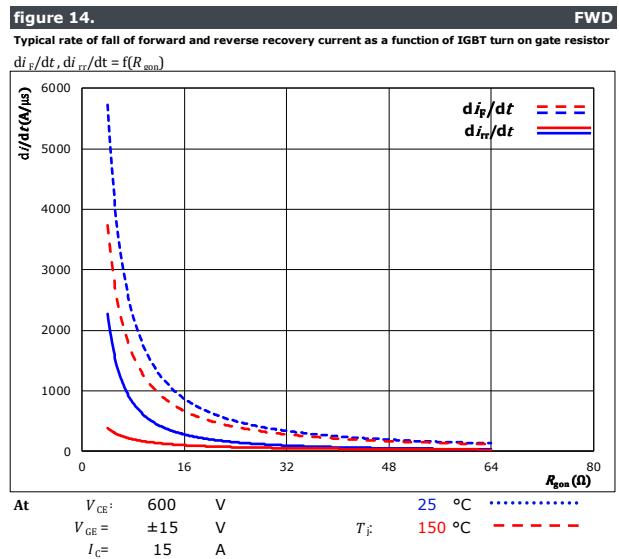
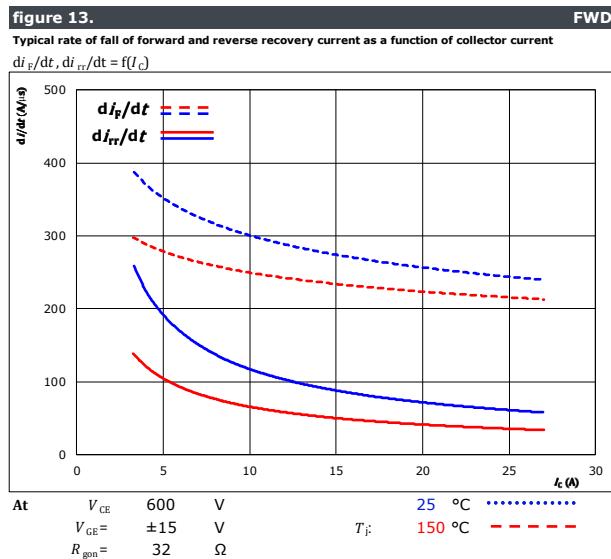




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Inverter Switching Characteristics





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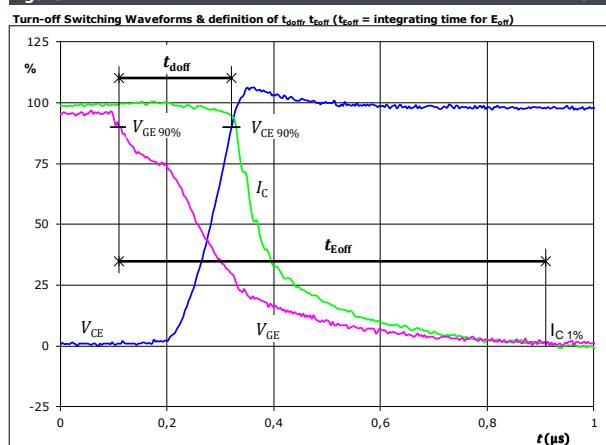
Inverter Switching Definitions

General conditions

T_i	=	150 °C
R_{gon}	=	32 Ω
R_{goff}	=	32 Ω

figure 1.

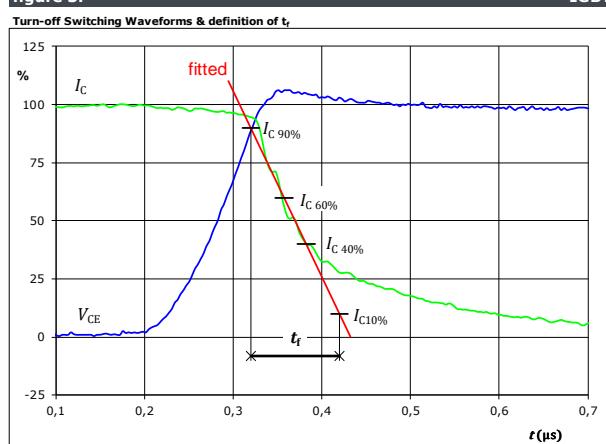
IGBT



$V_{GE}(0\%) = -15 \text{ V}$
 $V_{GE}(100\%) = 15 \text{ V}$
 $V_C(100\%) = 600 \text{ V}$
 $I_C(100\%) = 15 \text{ A}$
 $t_{doff} = 0,218 \mu\text{s}$
 $t_{coff} = 0,800 \mu\text{s}$

figure 3.

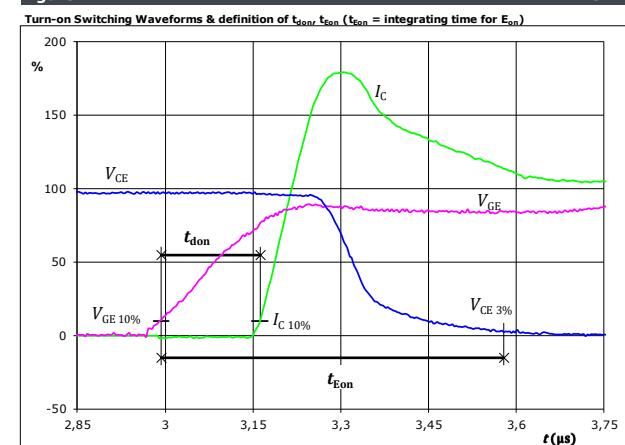
IGBT



$V_C(100\%) = 600 \text{ V}$
 $I_C(100\%) = 15 \text{ A}$
 $t_f = 0,127 \mu\text{s}$

figure 2.

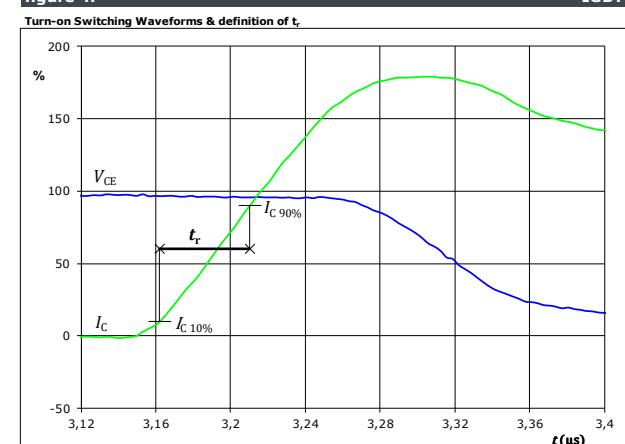
IGBT



$V_{GE}(0\%) = -15 \text{ V}$
 $V_{GE}(100\%) = 15 \text{ V}$
 $V_C(100\%) = 600 \text{ V}$
 $I_C(100\%) = 15 \text{ A}$
 $t_{don} = 0,174 \mu\text{s}$
 $t_{ion} = 0,586 \mu\text{s}$

figure 4.

IGBT

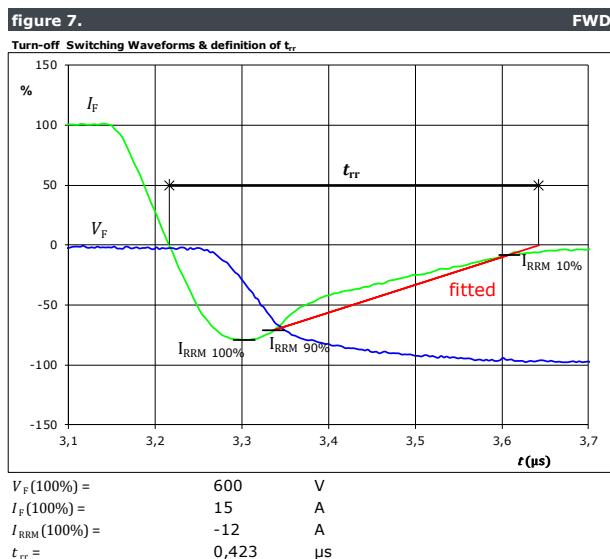
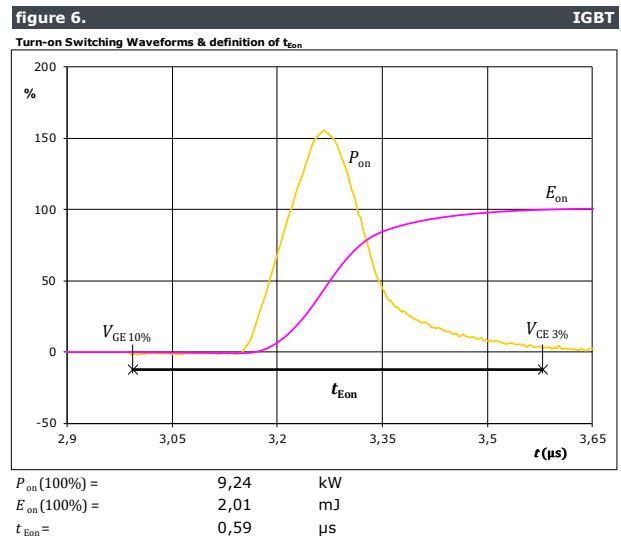
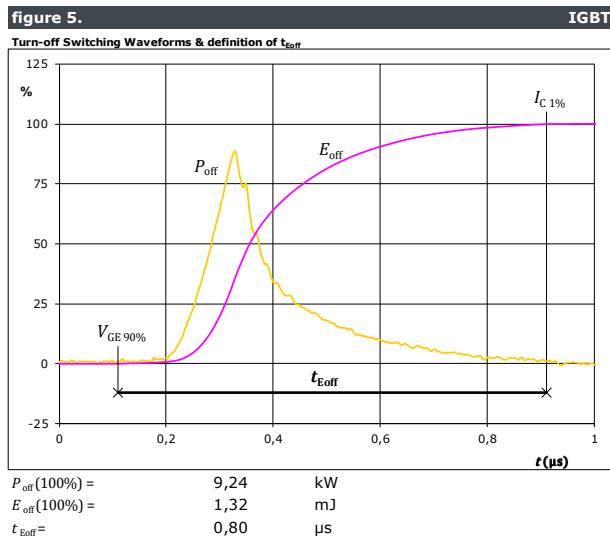


$V_C(100\%) = 600 \text{ V}$
 $I_C(100\%) = 15 \text{ A}$
 $t_r = 0,048 \mu\text{s}$



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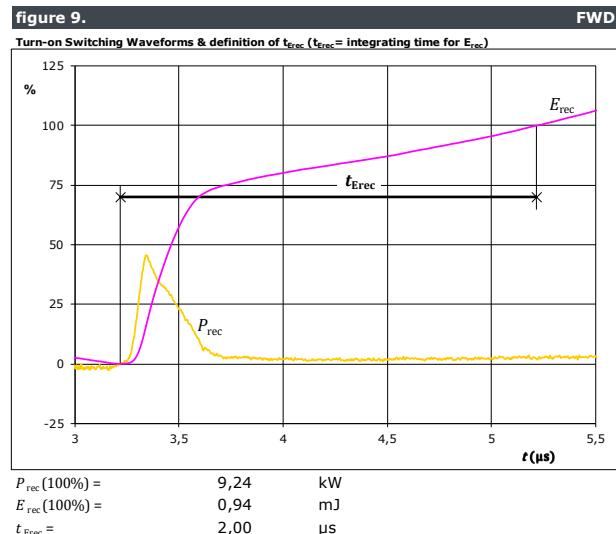
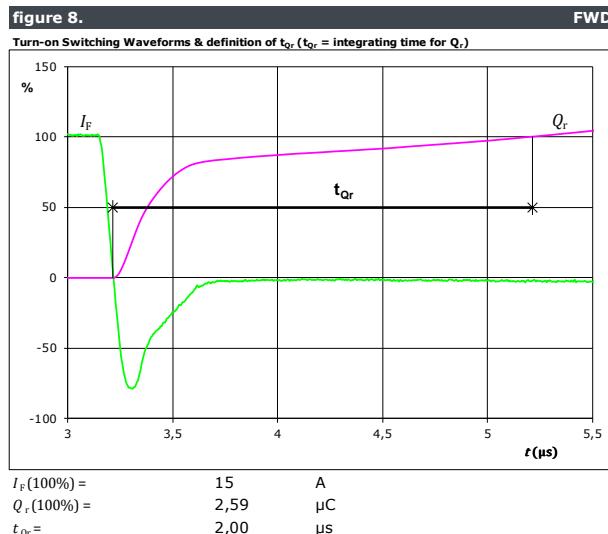
Inverter Switching Characteristics





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Inverter Switching Characteristics

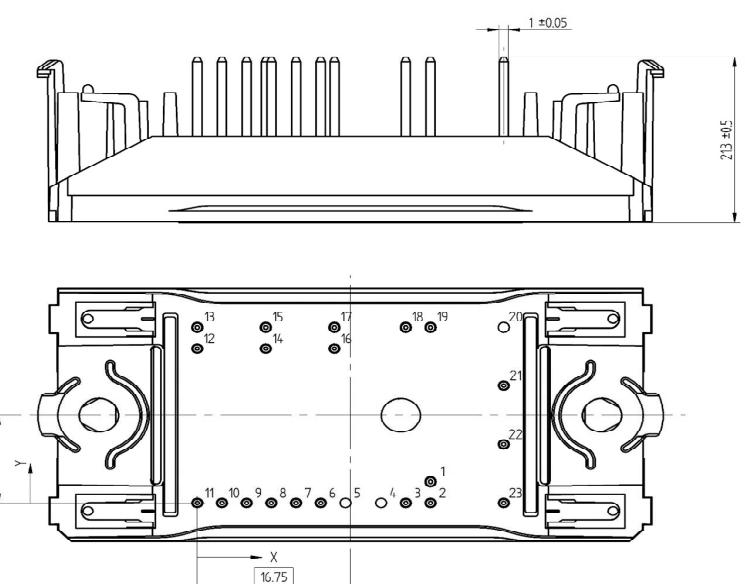




10-F012PNA015M7-P840C29

datasheet

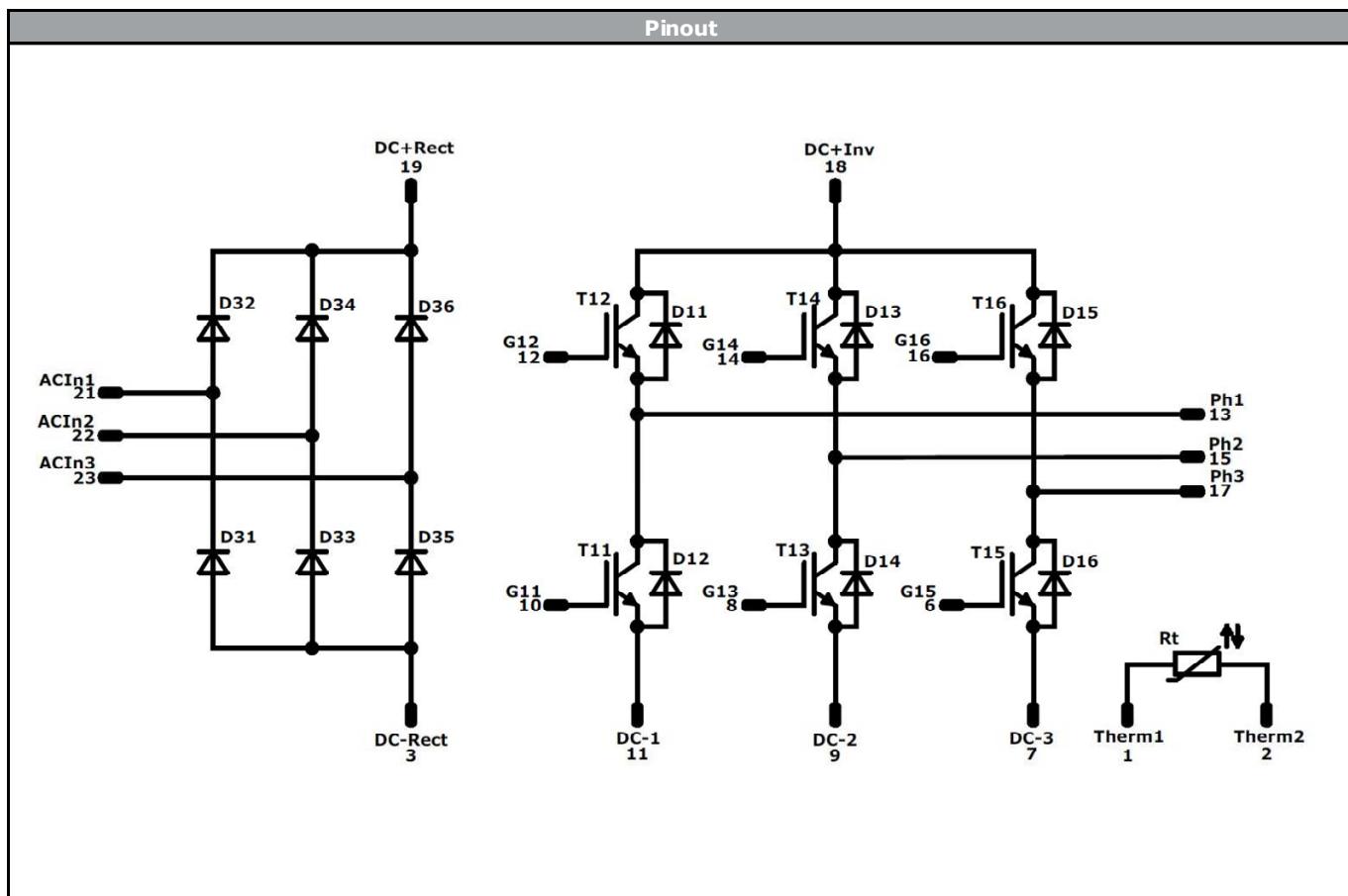
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Ordering Code & Marking							
Version				Ordering Code			
without thermal paste 17 mm housing with solder pins				10-F012PNA015M7-P840C29			
							
Text	Name	Date code	UL & VIN	Lot	Serial		
NN-NNNNNNNNNNNN TTTTVVV WWYY UL VIN LLLLL SSSS	NN-NNNNNNNNNNNNN-TTTTTVV	WWYY	UL VIN	LLLLL	SSSS		
Datamatrix	Type&Ver	Lot number	Serial	Date code			
	TTTTTVV	LLLLL	SSSS	WWYY			
Outline							
Pin table				 <p>1 ± 0.05</p> <p>213 ± 0.5</p> <p>Y</p> <p>X 16.75</p>			
Pin	X	Y	Function				
1	25,5	2,7	Therm1				
2	25,5	0	Therm2				
3	22,8	0	DC-Rect				
4	Not assembled						
5	Not assembled						
6	13,5	0	G15				
7	10,8	0	DC-3				
8	8,1	0	G13				
9	5,4	0	DC-2				
10	2,7	0	G11				
11	0	0	DC-1				
12	0	19,8	G12				
13	0	22,5	Ph1				
14	7,5	19,8	G14				
15	7,5	22,5	Ph2				
16	15	19,8	G16				
17	15	22,5	Ph3				
18	22,8	22,5	DC+Inv				
19	25,5	22,5	DC+Rect				
20	Not assembled						
21	33,5	15	ACIn1				
22	33,5	7,5	ACIn2				
23	33,5	0	ACIn3				

Tolerance of pinpositions: ±0.5mm at the end of pins
Dimension of coordinate axis is only offset without tolerance



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Identification					
ID	Component	Voltage	Current	Function	Comment
T11, T12, T13, T14, T15, T16	IGBT	1200 V	15 A	Inverter Switch	
D11, D12, D13, D14, D15, D16	FWD	1200 V	15 A	Inverter Diode	
D31, D32, D33, D34, D35, D36	Rectifier	1600 V	25 A	Rectifier Diode	
Rt	Thermistor			Thermistor	



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Packaging instruction			
Standard packaging quantity (SPQ) 135	>SPQ	Standard	<SPQ Sample

Handling instruction			
Handling instructions for flow 0 packages see vincotech.com website.			

Package data			
Package data for flow 0 packages see vincotech.com website.			

UL recognition and file number			
This device is certified according to UL 1557 standard, UL file number E192116. For more information see vincotech.com website.			

Document No.:	Date:	Modification:	Pages
10-F012PNA015M7-P840C29-D1-14	26 Jul. 2018	Initial release	

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